

# ECE-606: Spring 2013

## Course Introduction

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### course objectives

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*To **introduce** students to the fundamentals of semiconductors and semiconductor devices.*

## electron devices

### vacuum tube



Edison effect, 1880  
J.J. Thompson, 1897  
diode (Fleming, 1904)  
triode (De Forest, 1905)

### transistor



Bardeen, Brattain,  
Shockley, 1947

### integrated circuit



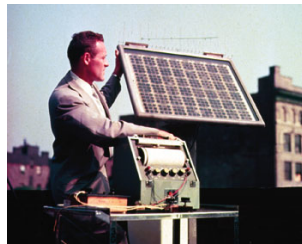
Kilby /Noyce, 1958

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3

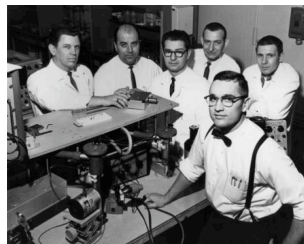
## electron devices

### modern solar cell



Chapin, Pearson, Fuller,  
1954

### LED



Holonyak, 1962

### semiconductor laser



Hall, 1962

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4

## Purdue's semiconductor history



“Karl Lark-Horovitz is best known for turning the physics department of Purdue University, then a backwater school, into a research powerhouse. His personal research was in germanium and solid state science -- and if anyone had had a chance of inventing the transistor before Bell, it was Lark-Horovitz. As it was, the Purdue physics lab was probably only six to twelve months behind.”

<http://www.pbs.org/transistor/album1/addlbios/lark.html>

1941: WWII: Semiconductor diode rectifiers  
<http://www.computerhistory.org>

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5

## electronics in the 21<sup>st</sup> Century



[www.apple.com](http://www.apple.com)

CMOS transistors for logic  
III-V transistors for RF  
A/D and D/A convertors  
Digital Signal processor  
Microprocessor  
ROM and FLASH memory

CMOS imager  
Gyroscope  
MEMS devices  
Magnetometer  
Microphone, speaker  
LCD display and touch screen

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6

## transistors

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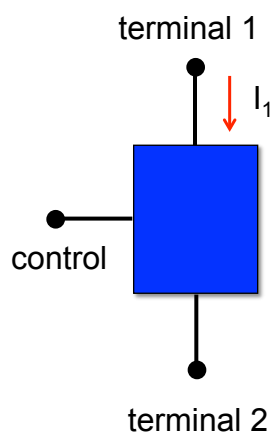
"The **transistor** was probably the most important invention of the 20th Century, and the story behind the invention is one of clashing egos and top secret research."

- Ira Flatow, Transistorized!

<http://www.pbs.org/transistor/>

## transistors

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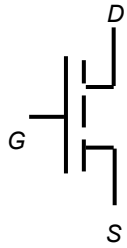


point contact transistor  
bipolar transistor  
MOSFET  
JFET  
SOI MOSFET  
SB FET  
FinFET  
MODFET (HEMT)  
heterojunction bipolar transistor  
velocity modulation transistor  
BTBT FET  
SpinFET

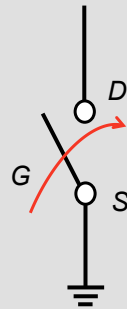
...

## uses for transistors

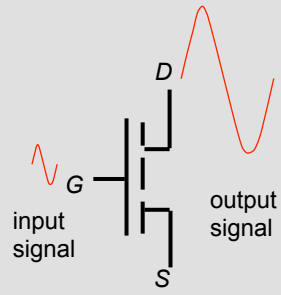
symbol



switch



amplifier

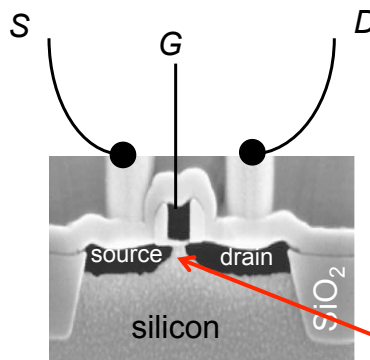
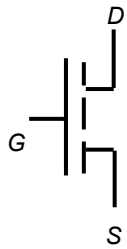


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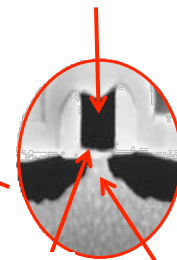
9

## real transistors

symbol



gate electrode



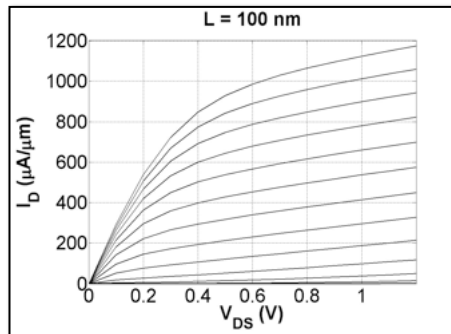
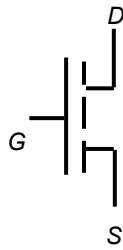
gate oxide  
SiON ~ 1.1 nm

channel  
~ 22 nm

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## transistor IV

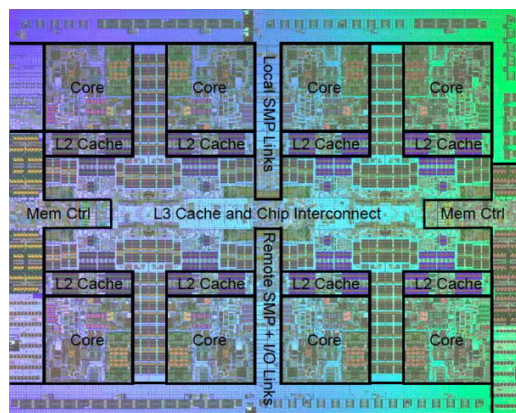
symbol



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11

## integrated circuits



IBM Power7 (45nm, 1.2B transistors)

<http://arstechnica.com/business/news/2010/02/two-billion-transistor-beasts-power7-and-niagara-3.ars>

12



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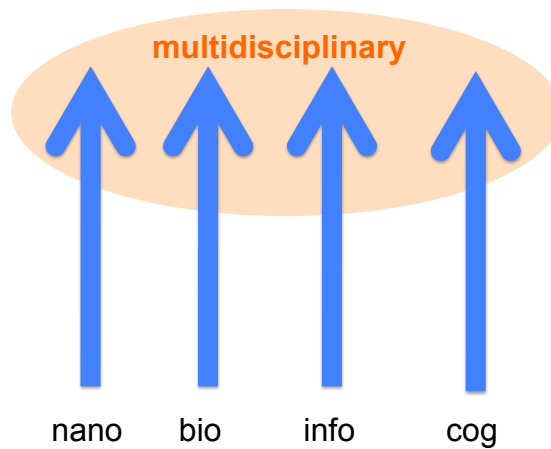
“The most important moment since man emerged as a life form.”

Isaac Asimov

(about the “planar process” used to manufacture ICs (invented by Jean Hoerni, Fairchild Semiconductor, 1959).

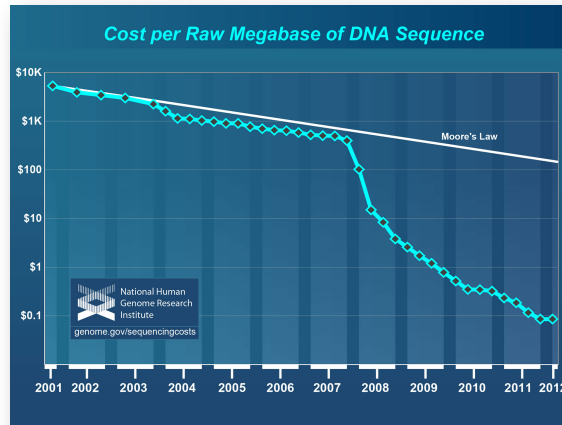
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“converging technologies”





## example: gene sequencing

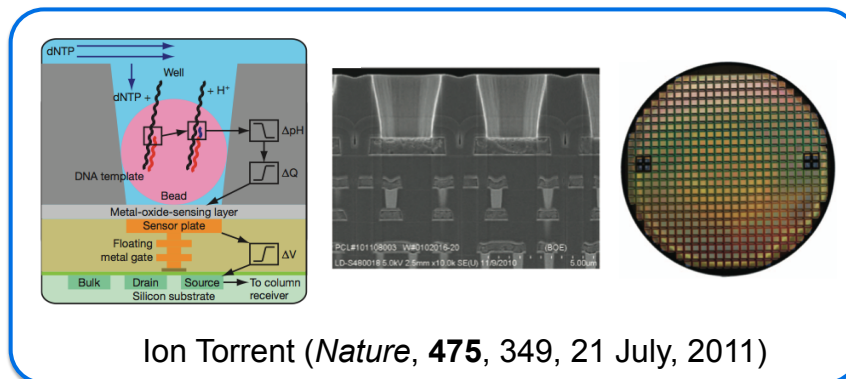


<http://www.genome.gov/sequencingcosts/>

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17

## Electronics beyond Moore's Law



Ion Torrent (*Nature*, **475**, 349, 21 July, 2011)

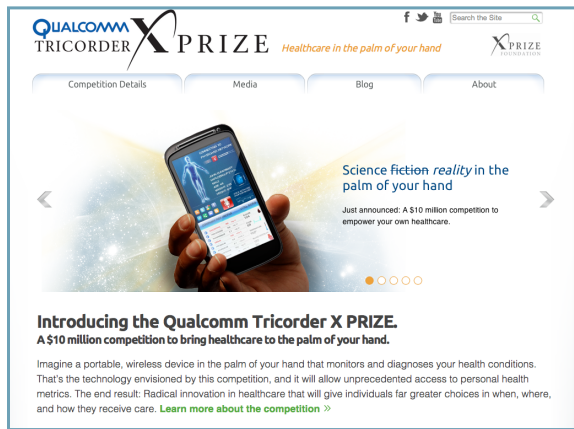
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18

# NBIC convergence

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## Electronics and healthcare



### Electronics and:

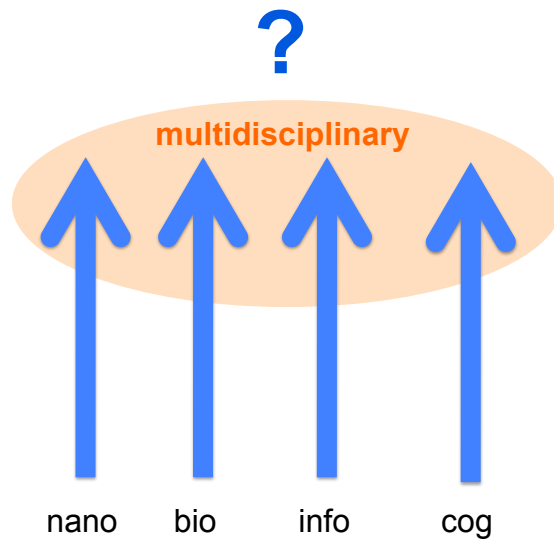
- Energy
- Environment
- Cognition
- Security
- Personalized learning
- ...

<http://www.qualcommtricorderxprize.org>

19

# transdisciplinary R&D

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20

## course outline

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<b>Part 1: Semiconductor Fundamentals:</b>	7 weeks
<b>Part 2: PN diodes, MS diodes, and LEDs</b>	2 weeks
<b>Part 3: Transistors</b>	6 weeks

## course texts

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*Advanced Semiconductor Fundamentals*, 2<sup>nd</sup> Edition (ASF)  
R.F. Pierret, Pearson Education, Inc., 2003.  
ISBN-0-13-061792-X (paperback)

*Semiconductor Device Fundamentals*, 2<sup>nd</sup> Edition (SDF)  
R.F. Pierret, Addison-Wesley Publishing Co, 1996.  
ISBN-0-201-54393-1

## course format: “flipped”

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### Week 1: Introduction / Geometry of Crystals

Reading Assignment: Applied Semiconductor Fundamentals, 2nd ed., R.F. Pierret, pp. 10-17

[ECE 606 Lecture 1: Introduction](#)

[Quiz 1 Week1Quiz1.pdf \(42.9 Kb\)](#)

[ECE 606 Lecture 2: Geometry of Periodic Crystals](#)

[Quiz 2 Week1Quiz2.pdf \(40.61 Kb\)](#)

Week 1 Homework Assignment [Week1HW.pdf \(132.86 Kb\)](#)

[Week 1 Homework Solution](#)

[Week 1: Answers to Quizzes](#)

[Week 1: References and Supplementary Information](#)

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<http://nanohub.org/groups/ece606lundstrom>

## grading

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**Lecture quizzes and questions: 25%**

**Exams (5 at 15% each) 75%**

Quiz score =  $x/\text{total}$  times 25%, where  $x$  is the number of quizzes you turned in and passed and total is the total number of lectures in the course.

Exam score = average of the percentage scores of the 5/6 best exams scores including any retake.

### Approximate curve:

A: 91 – 100%

B: 81 – 90%

C: 71 – 80%

D: 61 – 70%

F: 60% or less

## Steven Chu:

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“Learning science and thinking about science or reading a paper in science is not about learning what a person did. You have to do that, but **to really absorb it, you have to turn it around** and cast it in a form as if you invented it yourself. You have to look and be able to see things that other people looked at and didn't see before.

How do you do that? There are two ways. Either you make a new instrument, and it gives you better eyes, ... Or you **try to internalize it in such a way that it really becomes intuitive.**

## questions

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